

Interlayer Elasticity and Friction in 1D and 2D Van der Waals Materials

Elisa Riedo

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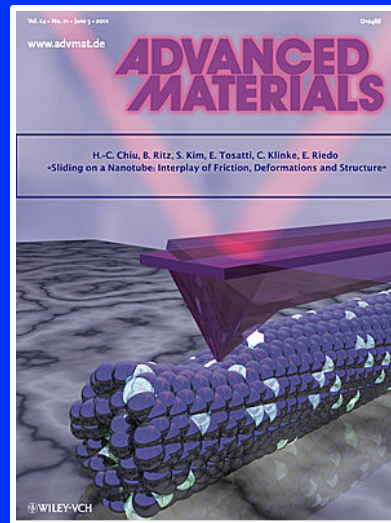
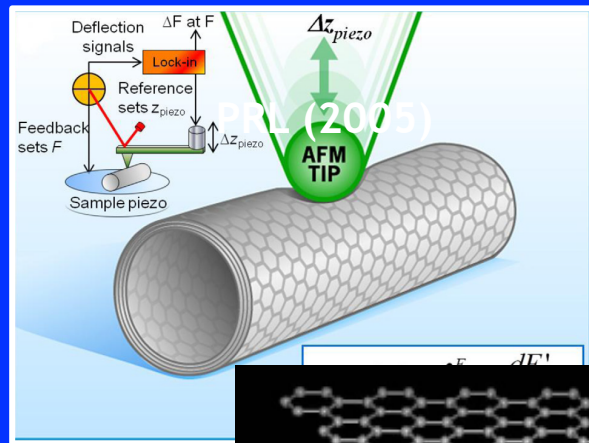


Nanomechanics by Atomic Force Microscopy

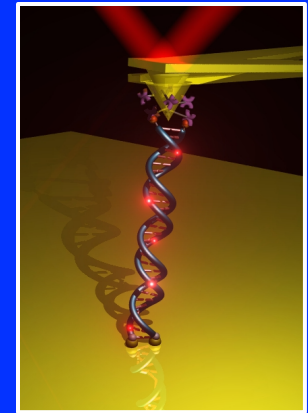
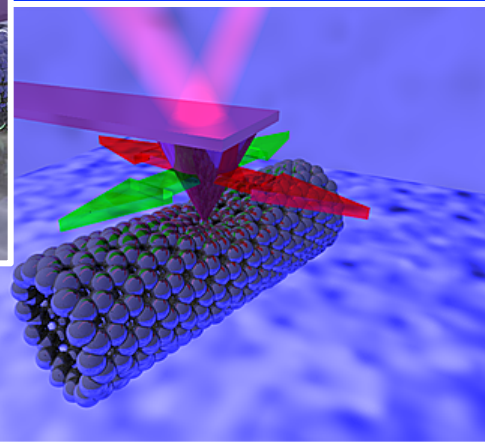
Radial Elasticity of NTs

Friction Anisotropy in NTs

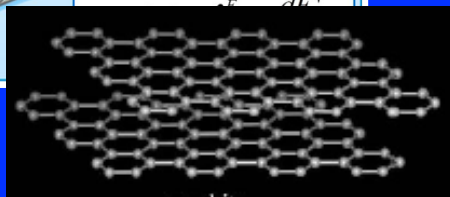
Stretching Modulus of short DNA strands



Nature Material (2010)



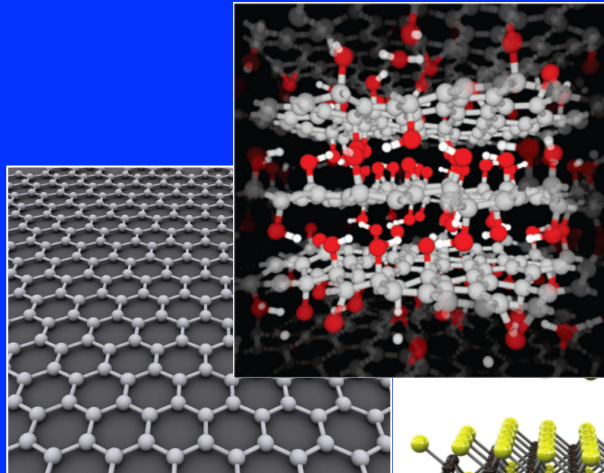
Nanoscale (2014)



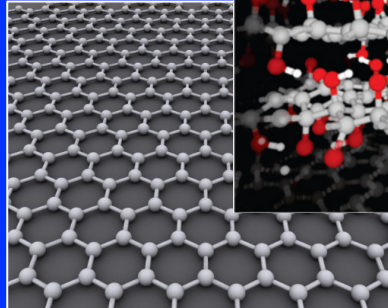
Nature Material (2015)



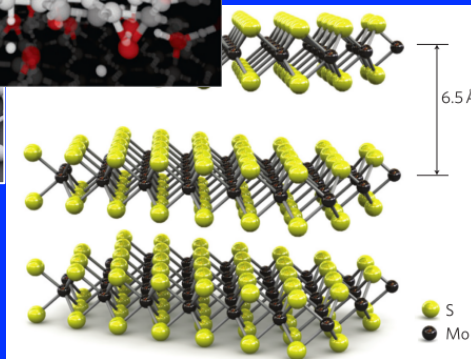
2D and 1D Layered Materials



Graphene Oxide

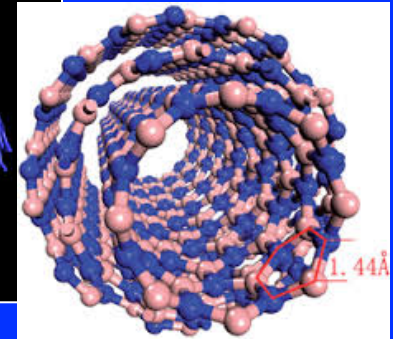
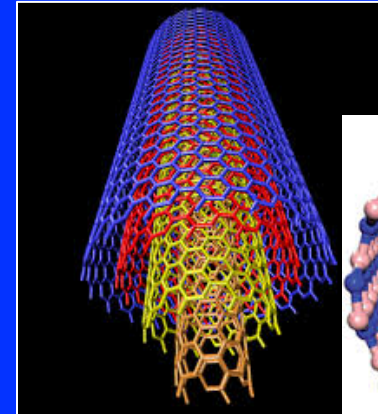


Graphene



MoS₂

C- Nanotubes



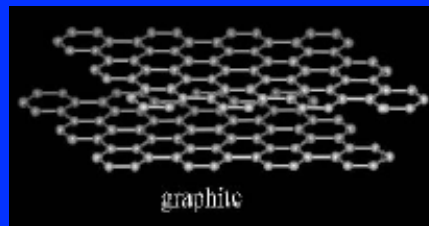
BN- Nanotubes

Key-Property:

**Strong In-Plane bonds and
Weaker Interlayer Interaction (Van der Waals force)**

$$C_{11} = 1.06 \text{ TPa}$$

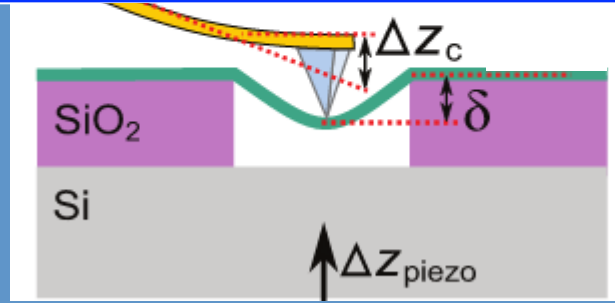
$$\longleftrightarrow E_{//}$$



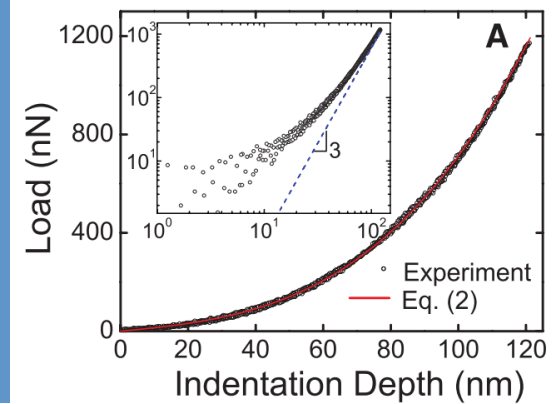
$$C_{33} = 36 \text{ GPa}$$

$$\updownarrow E_{\perp}$$

$$E_{//}$$



C. Lee *et al.*, Science (2008)

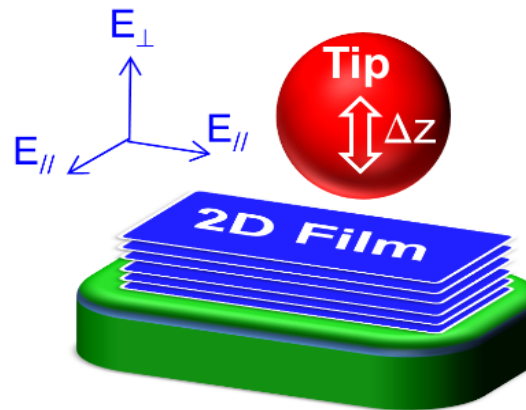


1. $\Delta Z \sim 10$ to 100nm ; 2. material suspended; 3. Only $E_{//}$ but not E_{\perp} !

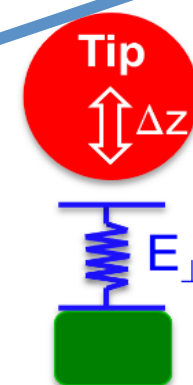
$< 0.3 \text{ nm}$

Supported on substrate

$$E_{\perp}$$



$\Delta z < 1\text{nm}$
 \approx



ARTICLES

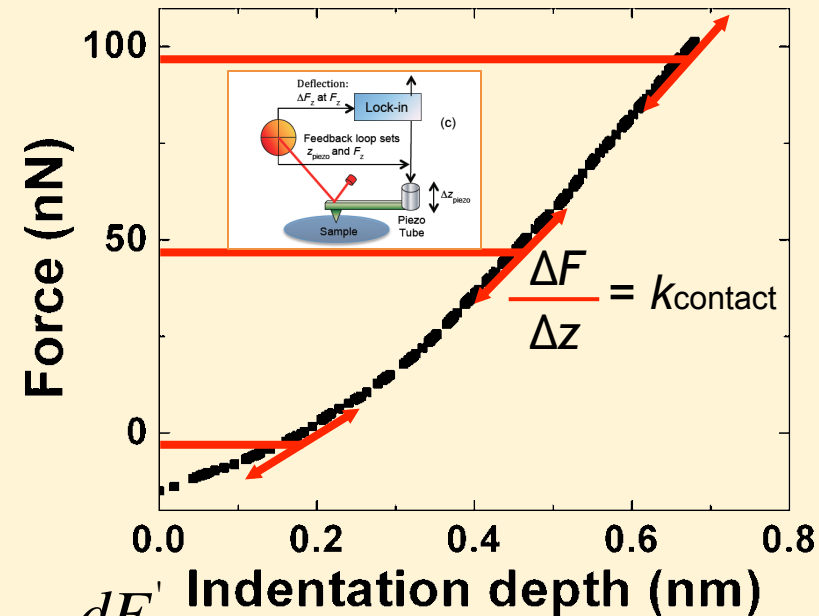
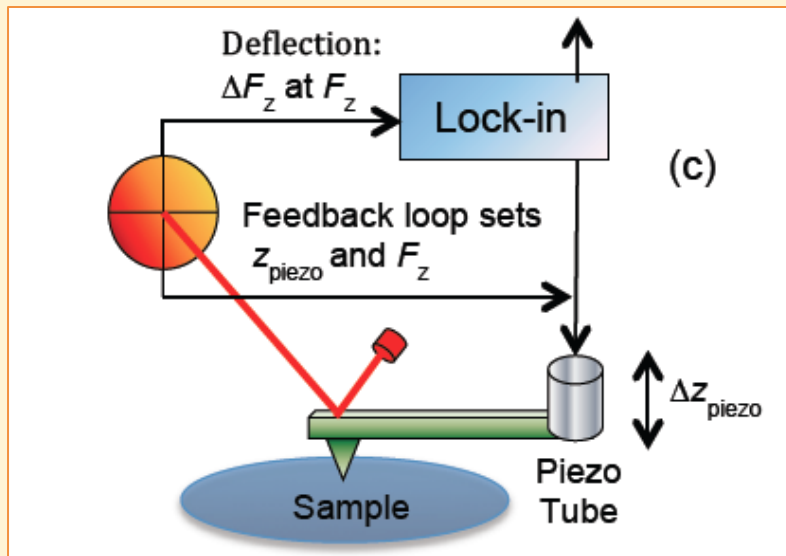
PUBLISHED ONLINE: 15 JUNE 2015 | DOI: 10.1038/NMAT4322

nature
materials

Elastic coupling between layers in two-dimensional materials

Yang Gao^{1,2†}, Suenne Kim^{3†}, Si Zhou¹, Hsiang-Chih Chiu⁴, Daniel Nélías⁵, Claire Berger^{1,6}, Walt de Heer^{1,7}, Laura Polloni⁸, Roman Sordan⁸, Angelo Bongiorno^{1,9*} and Elisa Riedo^{1,2*}

Modulated NanoIndentation (MoNI)



$$z(F) - z(F = 0) = \int_{F(z=0)}^{F_{\text{max}}} \frac{dF'}{k_{\text{contact}}(F')}$$

A new technique-*Modulated NanoIndentation* (MoNI):
FIRST experimental measurement of the local perpendicular-to-the-plane elastic modulus E_{\perp} of 2D material at 0.1 Å resolution

Y. Gao, S. Zhou, S. Kim, H.-C. Chiu, D. Nélías, C. Berger, W. de Heer, L. Polloni, R. Sordan, A. Bongiorno and E. Riedo, *Nature Mat.* (2015)

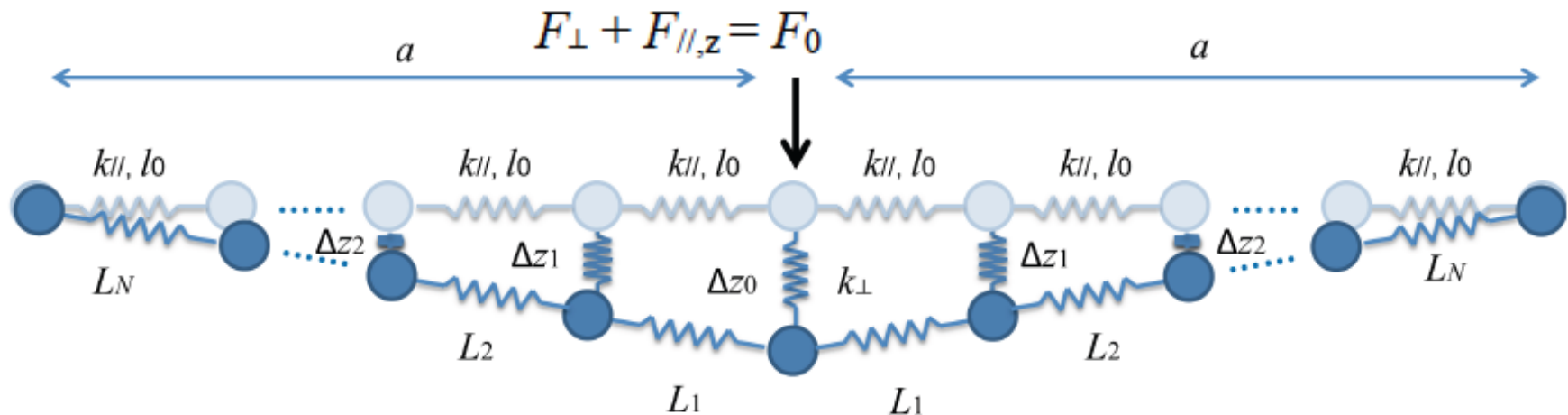
M. Lucas, W.J. Mai, R.S. Yang, Z.L. Wang, E. Riedo, *Phil. Mag.* 87, 2135 (2007)

M. Lucas, K. Gall, and E. Riedo, *J. Appl. Phys.* 104, 113515 (2008)

I. Palaci, C. Klink, H. Brune, E. Riedo, *Phys. Rev. Lett.* (2005)

Back-of-the-envelope Calculations

What do we measure when we indent a nano-size tip for indentations smaller than interlayer distance ?



$$\frac{F_{\perp}}{F_{\parallel,z}} = \frac{\Delta z_0 \times k_{\perp} \times N}{2k_{\parallel} \times \frac{\Delta z_0}{N} \times \frac{\Delta z_0}{a} \times \frac{\Delta z_0}{a}} = \frac{k_{\perp}}{2k_{\parallel}} \cdot \frac{N^2 a^2}{\Delta z_0^2}$$

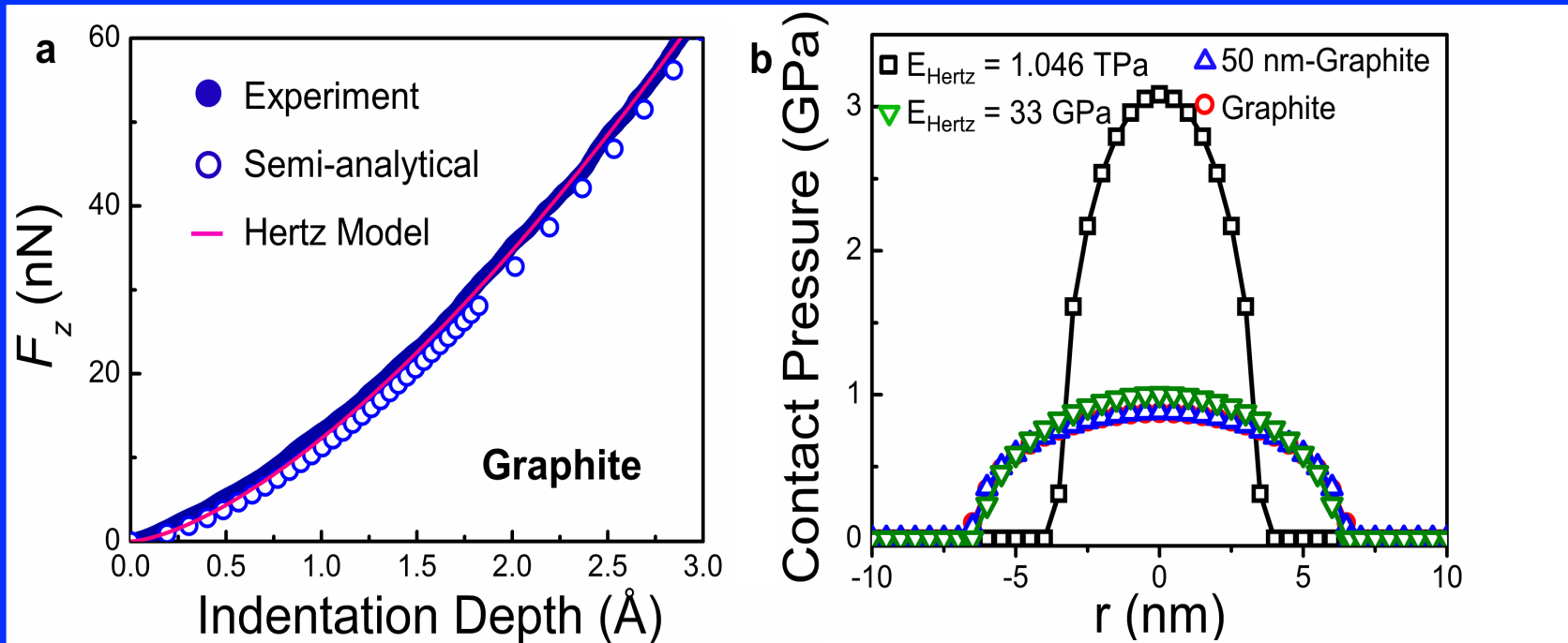
IF $\Delta z < 3 \text{ \AA}$

$$F_{\perp} / F_{\parallel,z} = 10^4 \gg 1$$

For sub-nm indentations \ll film thickness,
the force vs. indentation curves are mainly sensitive to E_{\perp} !

MoNI Å - depth indentations in 2D films

For sub-nm indentations \ll film thickness, the force vs. indentation curves are mainly sensitive to E_{\perp} !



Graphite: $E_{//} = 1.046$ TPa and $E_{\perp} = (36.4 \pm 1)$ GPa

Hertz model as if graphite was isotropic
with modulus = 33 GPa \rightarrow WORKS!
or 1.046 TPa \rightarrow Not good

2D Films: Graphene and Graphene Oxide

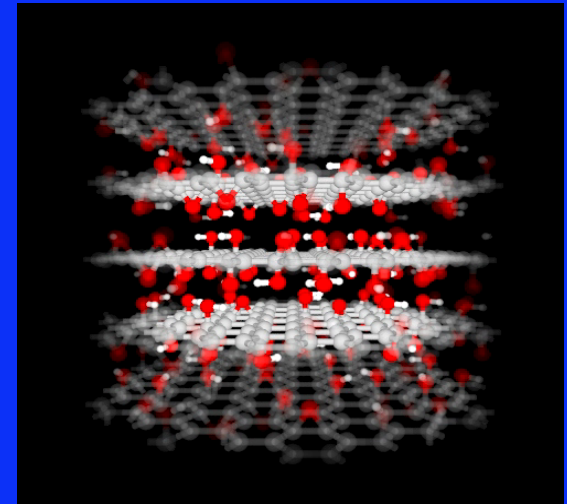
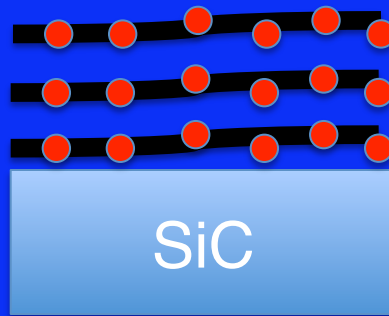
Graphene

Interlayer distance
 $\sim 3 \text{ \AA}$



Graphene Oxide

Interlayer distance
 $\sim 9 \text{ \AA}$



DFT Calculations From
Bongiorno's Lab

Controlled Functionalization of Graphene
has been explored as a route to produce
Graphene-based materials
with tunable mechanical, optical and electron transport properties

for Energy, Sensors, MEMS and Electronic Applications.

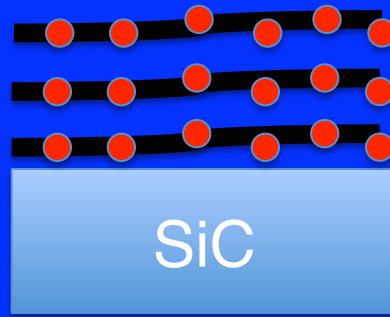
Epitaxial Multilayer Graphene Oxide (EGO)

Chemical (Hummers) Mild Oxidation of Epitaxial Graphene on SiC

Interlayer distance
 $\sim 3 \text{ \AA}$



Interlayer distance
 $\sim 9 \text{ \AA}$



- uniform films
- insulating
- transparent
- reproducible
- many potential applications

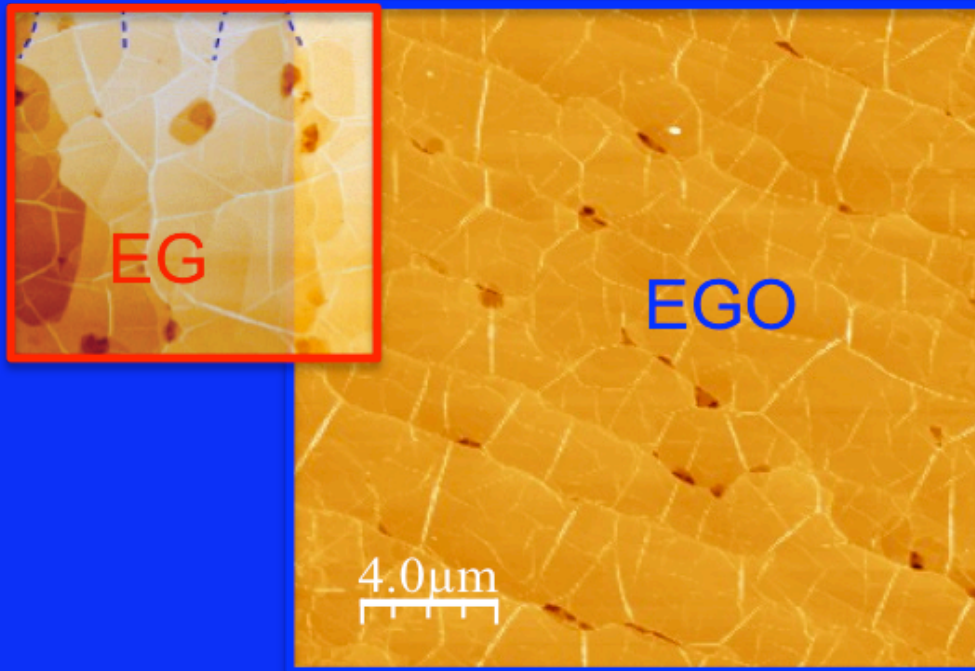
Nature Materials 11, 544 (2012)
Adv. Funct. Mat. (2015)
Science (2010)

Graphene films are epitaxially grown on the C-surface of a SiC .

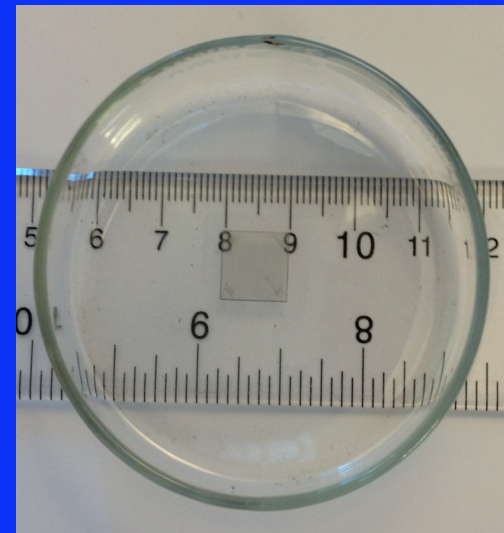
First, EG films are dipped into a $\text{H}_2\text{SO}_4/\text{NaNO}_3$ solution placed in an iced water bath. Second, KMnO_4 is added to the solution. The mixture is then transferred to a 35 C water bath for about 20 minutes. DI water (23 ml) is added slowly to the mixture. Finally, after 15 minutes, warm DI water (70 ml) and H_2O_2 (1.5 ml) are added to terminate the reaction. The sample is then brought in air, rinsed with DI water, and dried in a high purity nitrogen gas.

Epitaxial Multilayer Graphene Oxide (EGO)

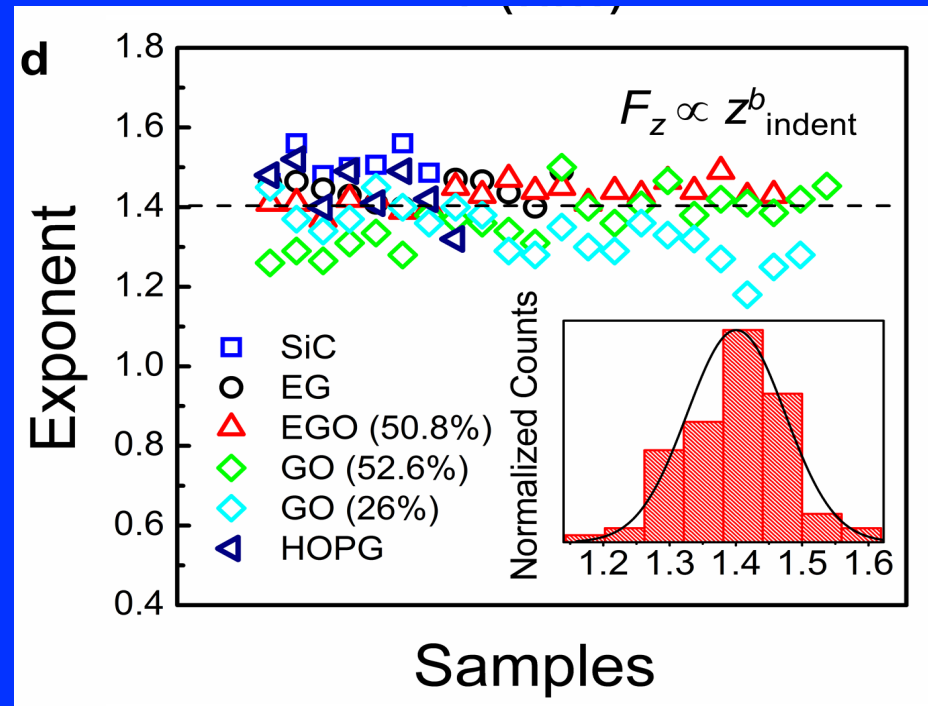
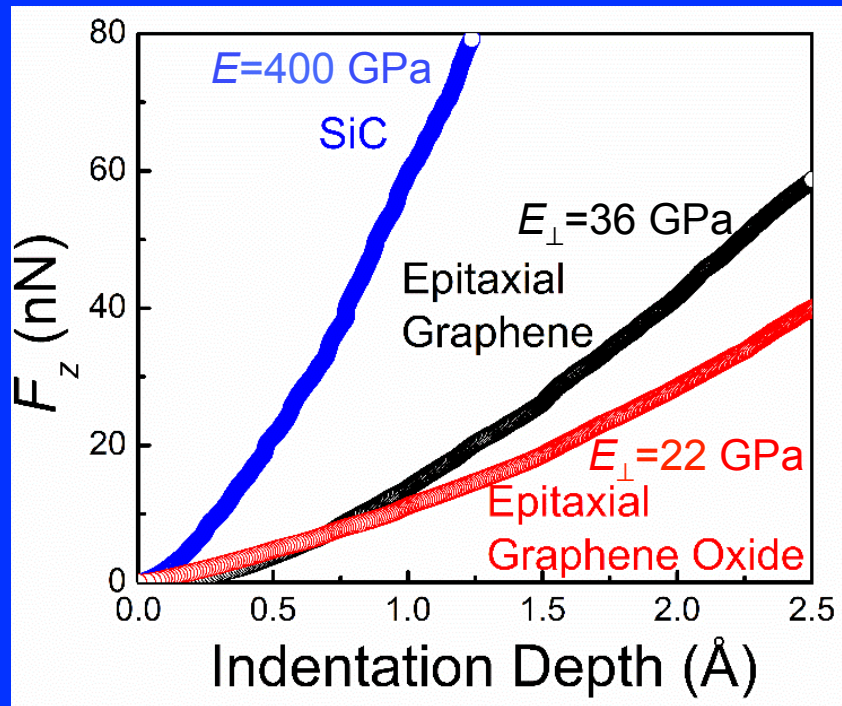
Chemical (Hummers) Mild Oxidation of Epitaxial Graphene on SiC



- uniform films
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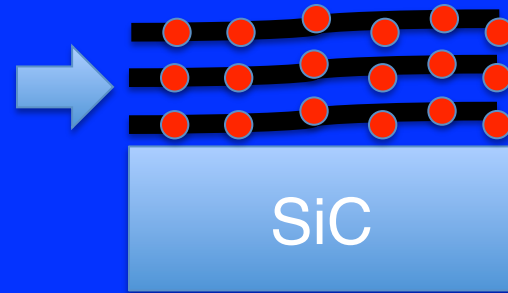
SiC, Epitax-Graphene (10-L), Epitax Graphene Oxide (10-L)



Riedo et al. Nature Materials
11, 544 (2012)
Riedo et al. Adv. Funct. Mat.
(2015)

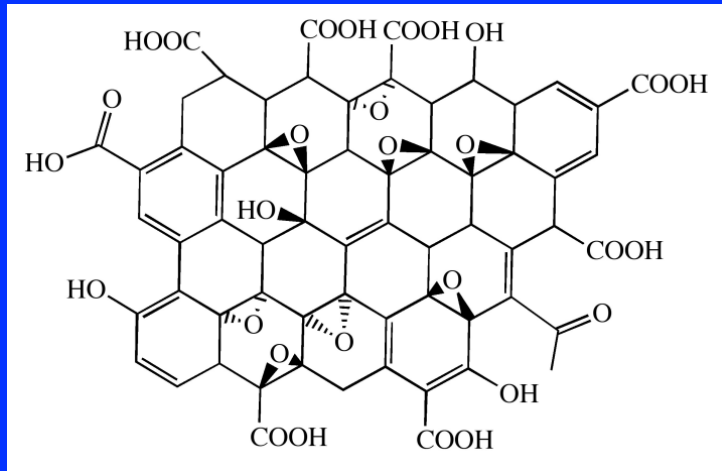


Epitaxial Graphene
(EG)



Epitaxial Graphene Oxide
(EGO)

Conventional Graphene Oxide Flakes



(1) Oxidation of bulk graphite:
The Hummers method
A Wet Chemistry Strong Acids Process

(2) Exfoliation in water



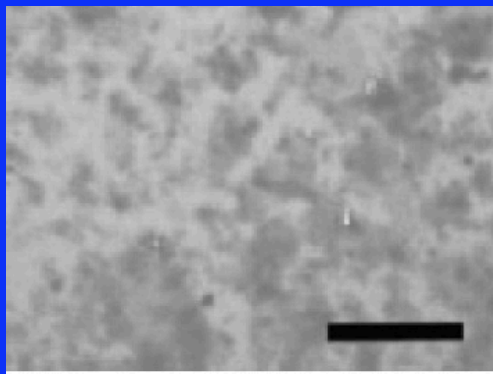
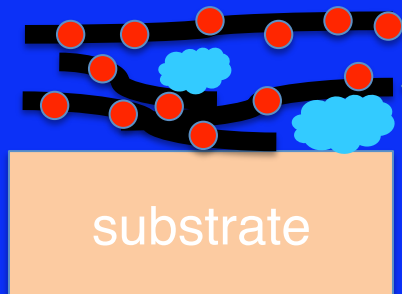
(3) Filtration and Deposition on a Substrate



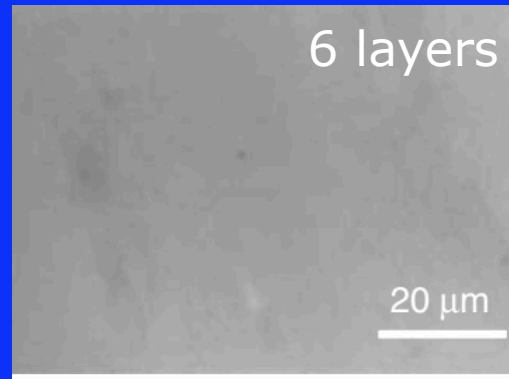
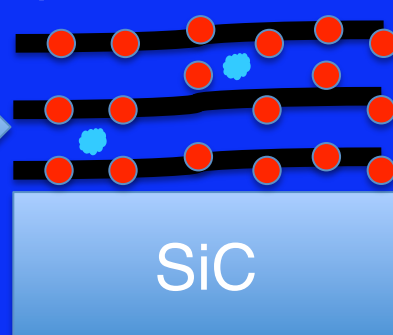
R.Ruoff, et. al. Nature 448, 457 (2007).

Epitaxial GO versus Flakes GO

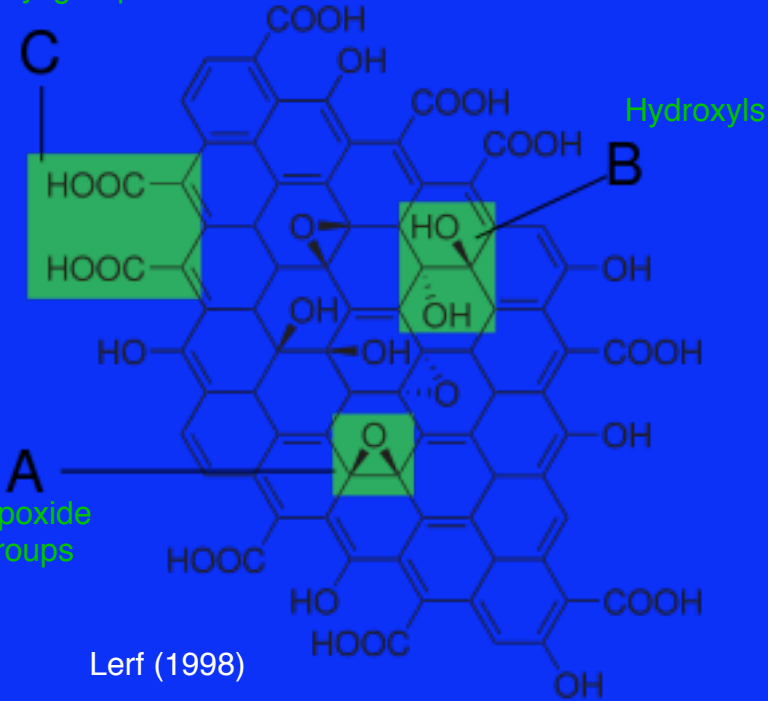
Conventional GO flakes films



Epitaxial GO films



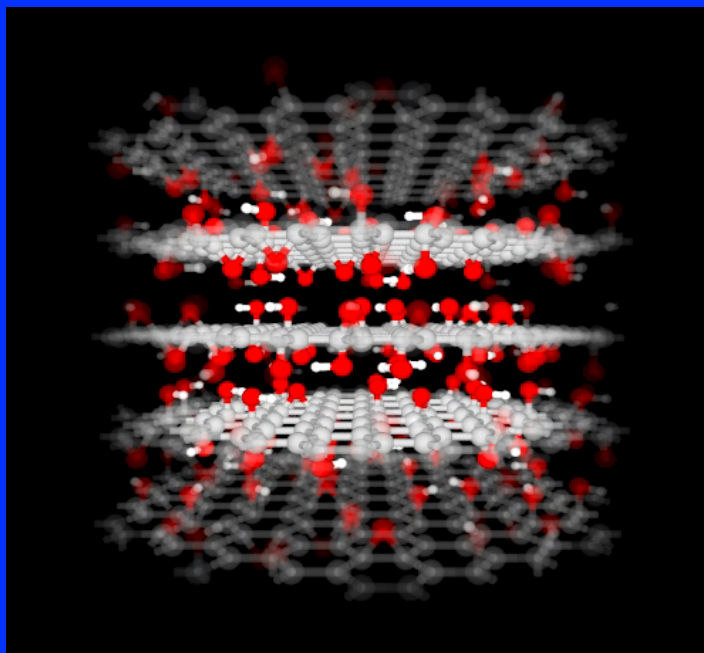
Carboxyl groups



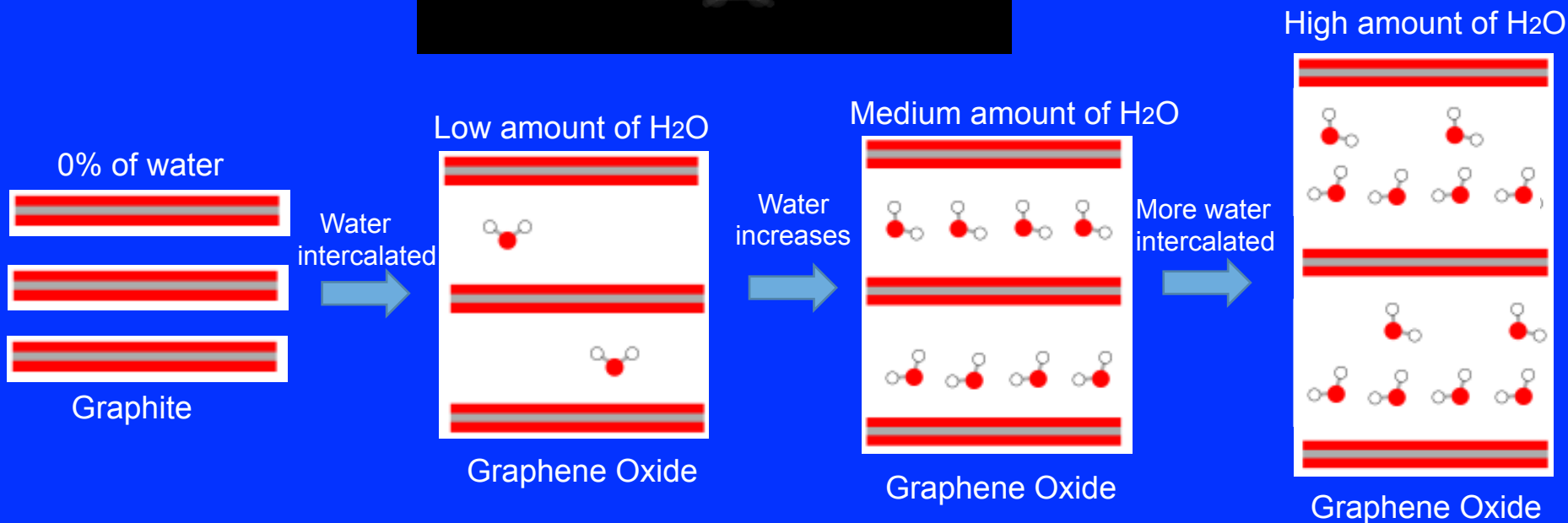
EGO films:

No edges (no carboxyl groups), uniform surface, control over number of layers, little water

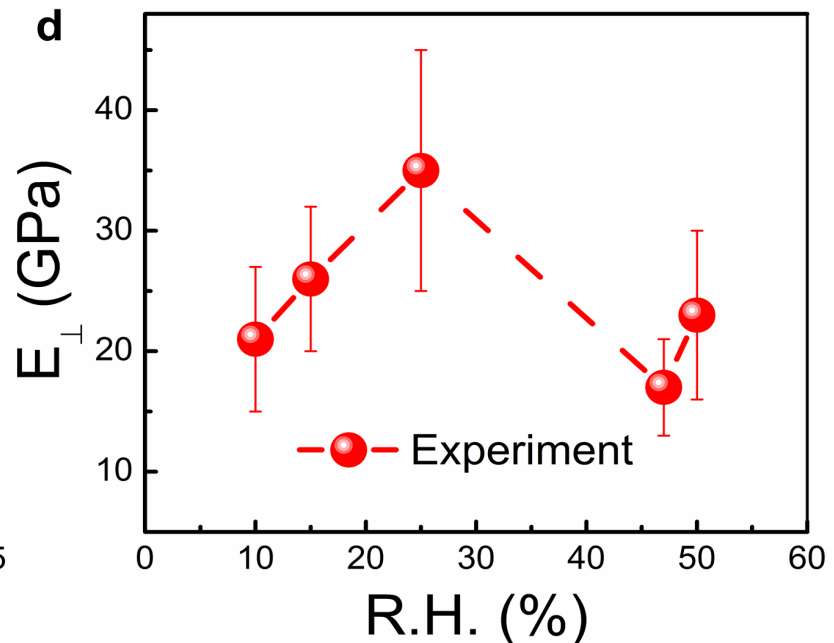
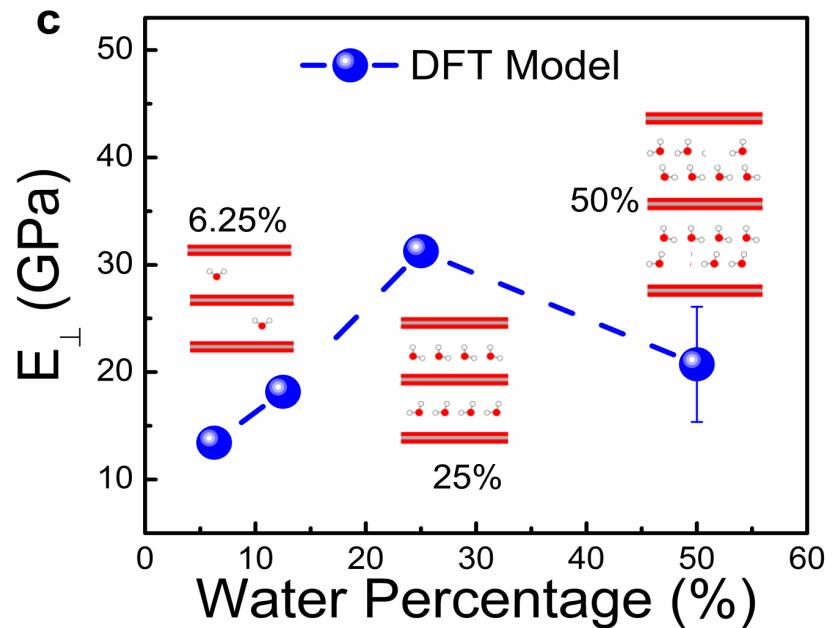
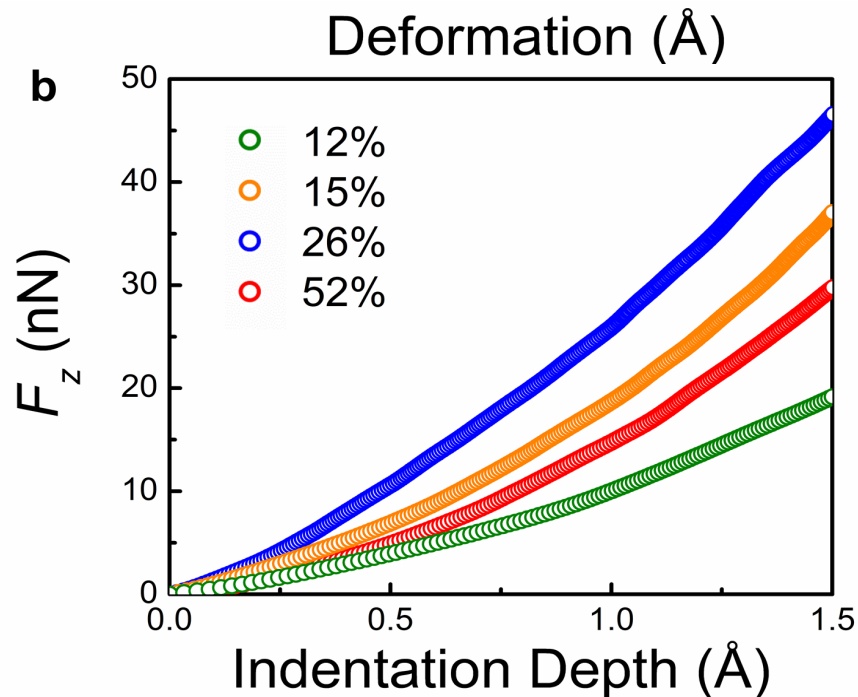
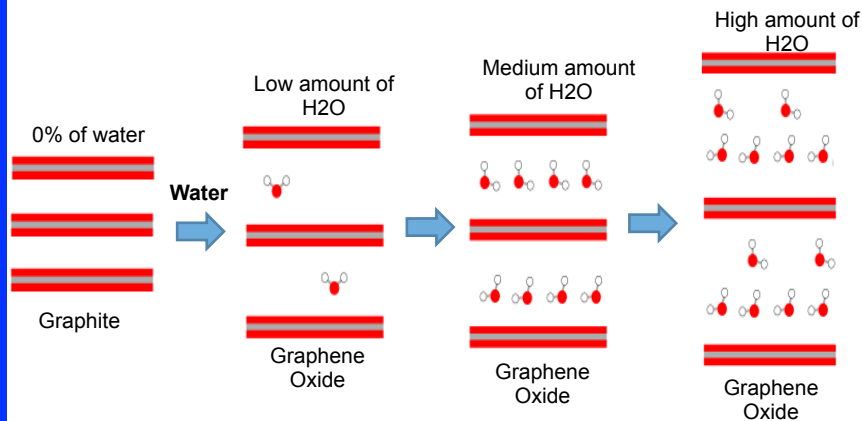
Conventional Graphene Oxide Flakes and Intercalated Water



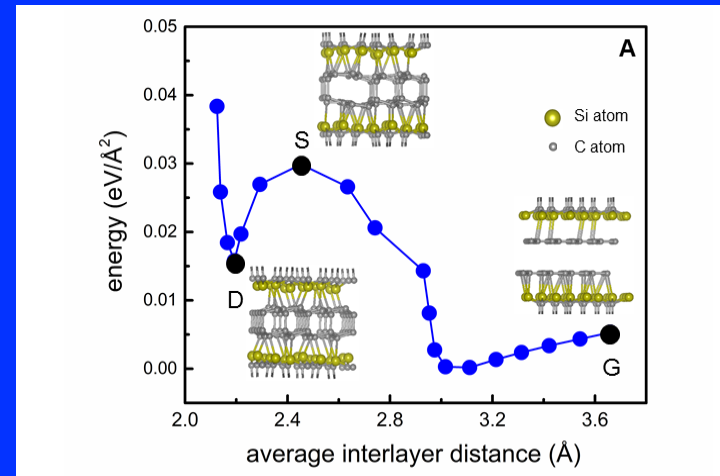
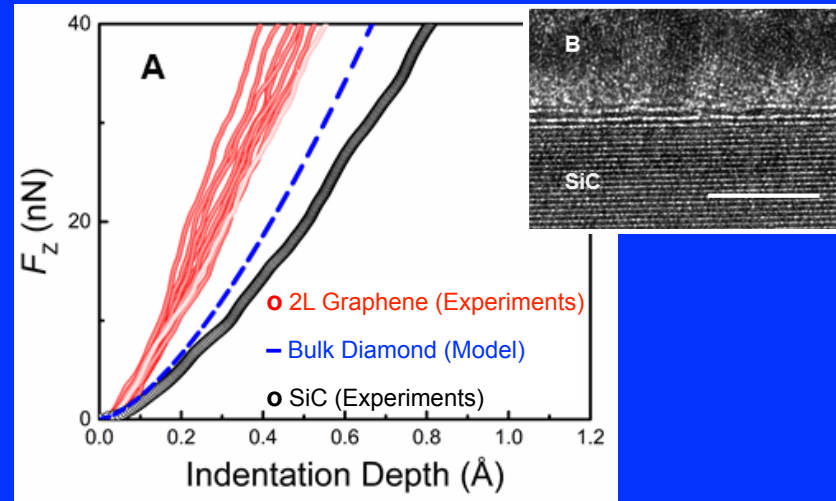
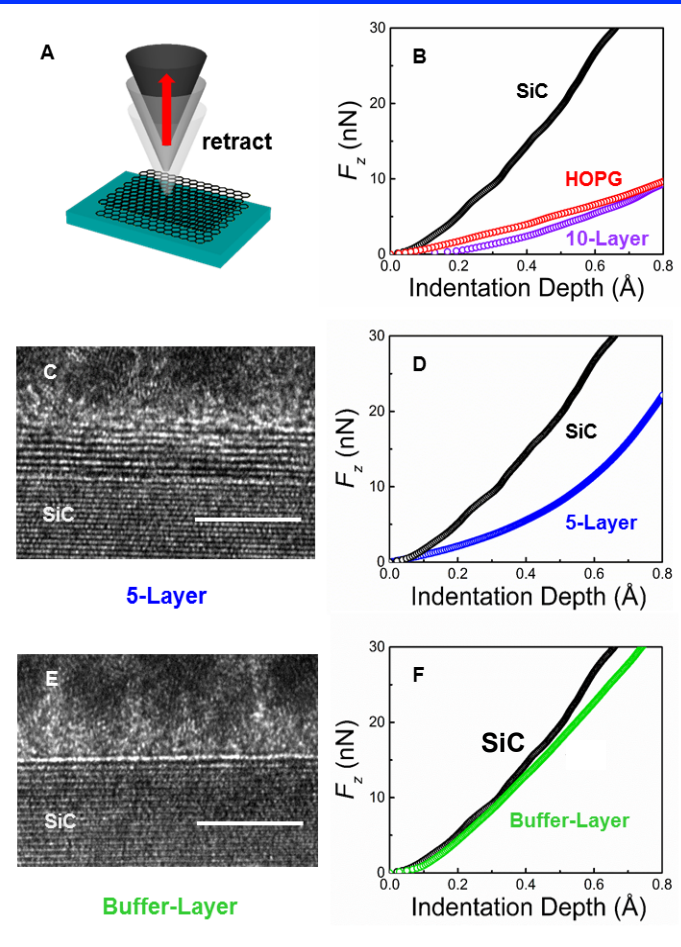
DFT Simulations from
Bongiorno's group



Graphene Oxide Interlayer Elasticity and Water

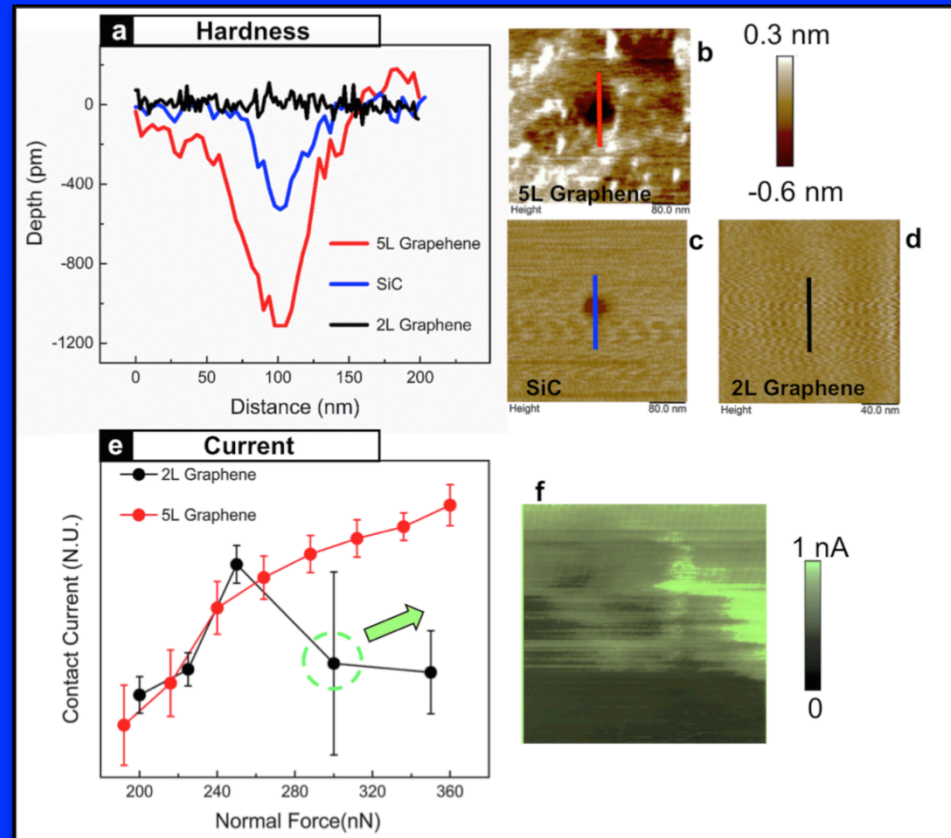


Inducing a diamond-stiff phase in two-layer graphene: the fingerprint of diamene



Under Review

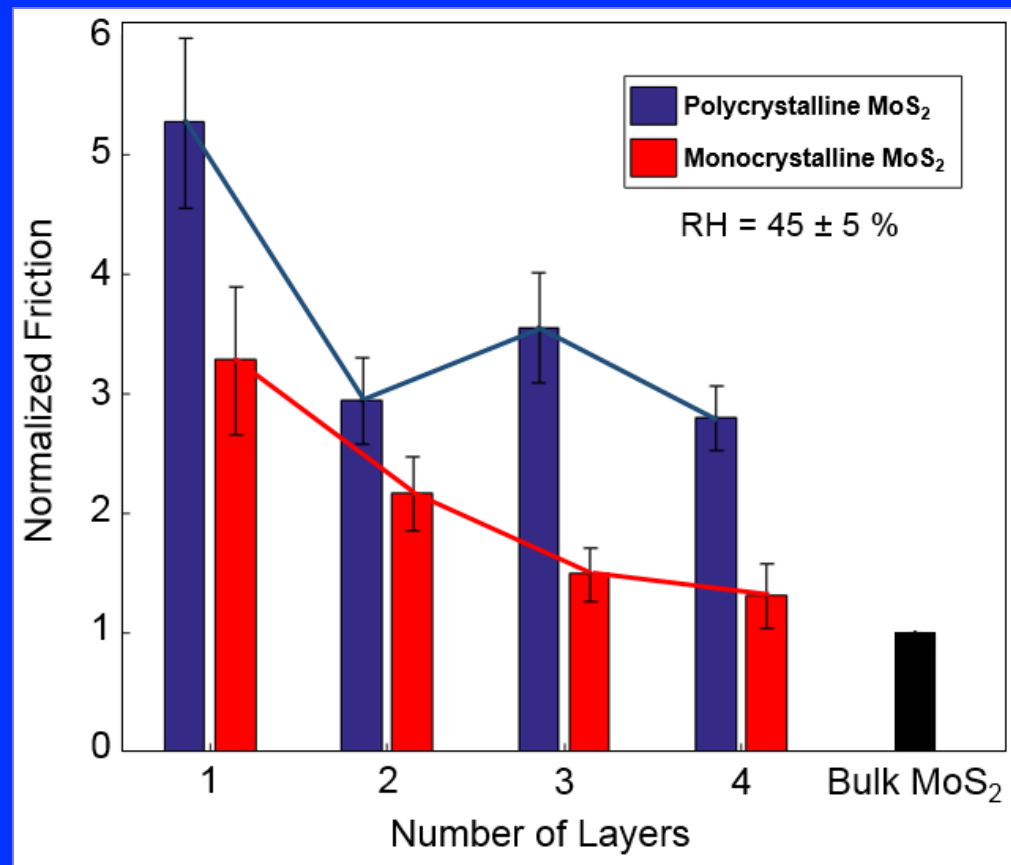
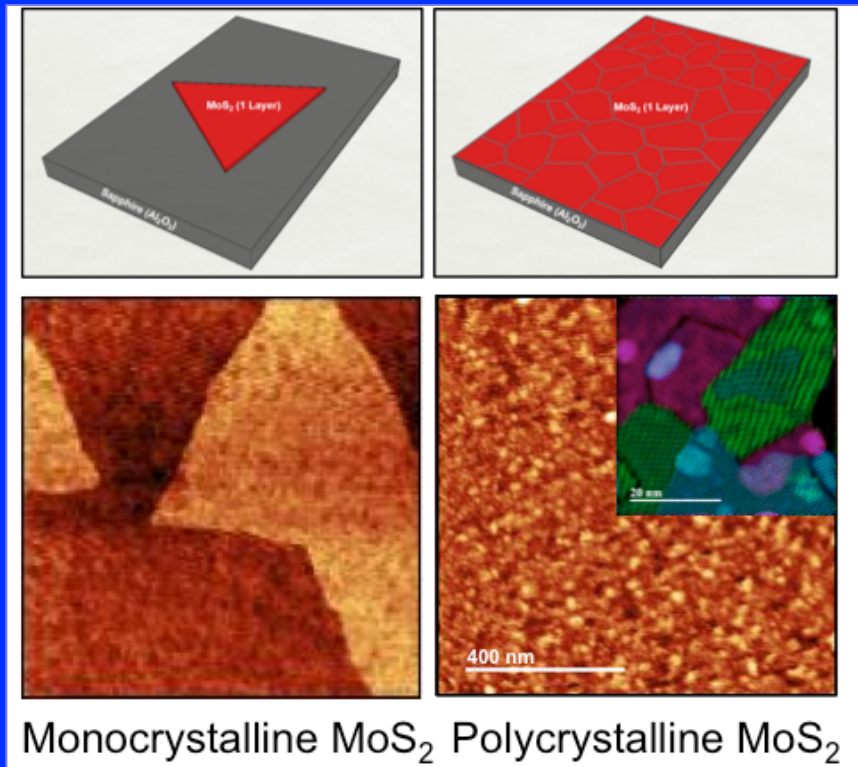
Inducing a diamond-stiff phase in two-layer graphene: the fingerprint of diamene



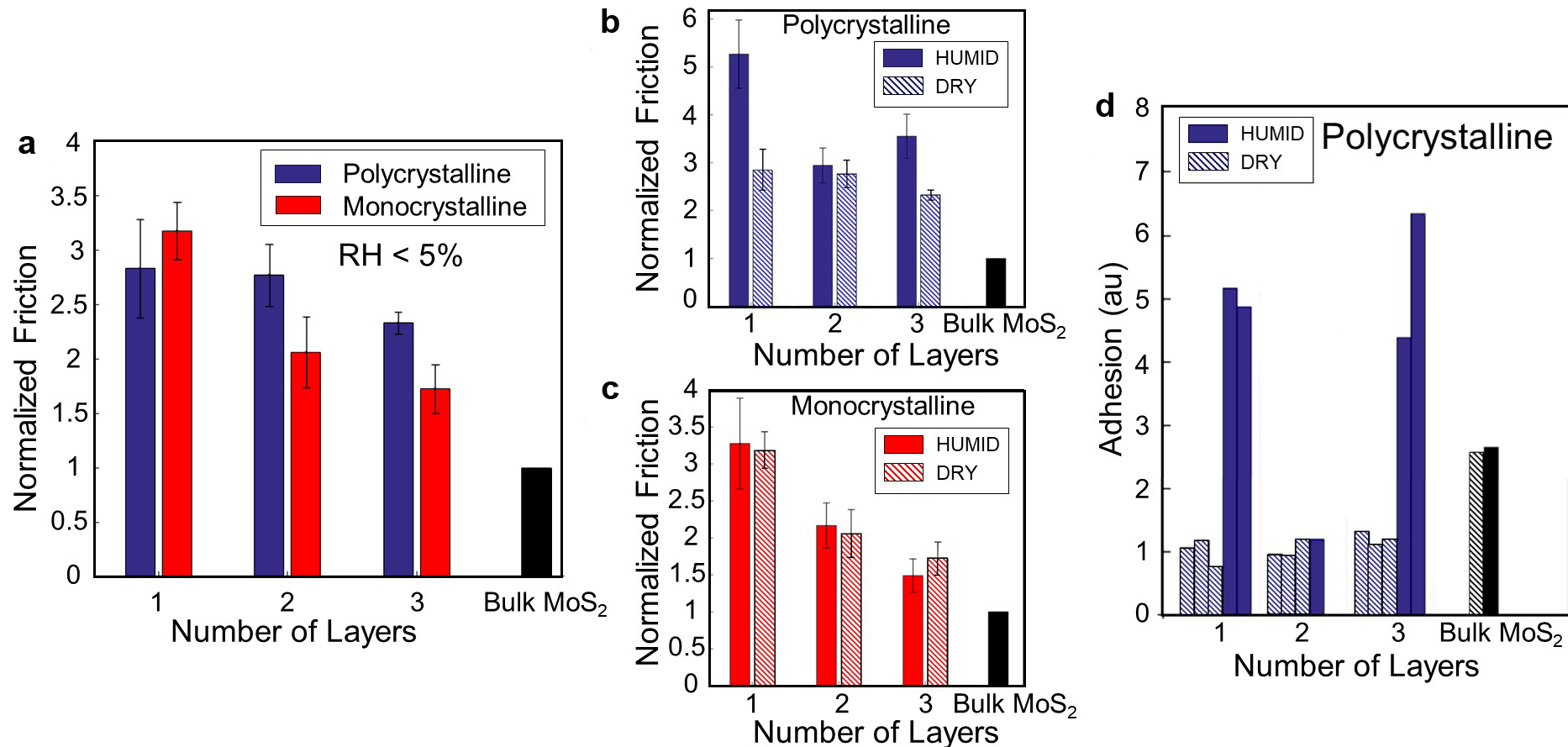
Under Review

Yang Gao*, Tengfei Cao*, Claire Berger, Walt de Heer, Tosatti, Angelo Bongiorno and Elisa Riedo

Oscillatory friction behavior for even and odd number of layers in polycrystalline MoS_2

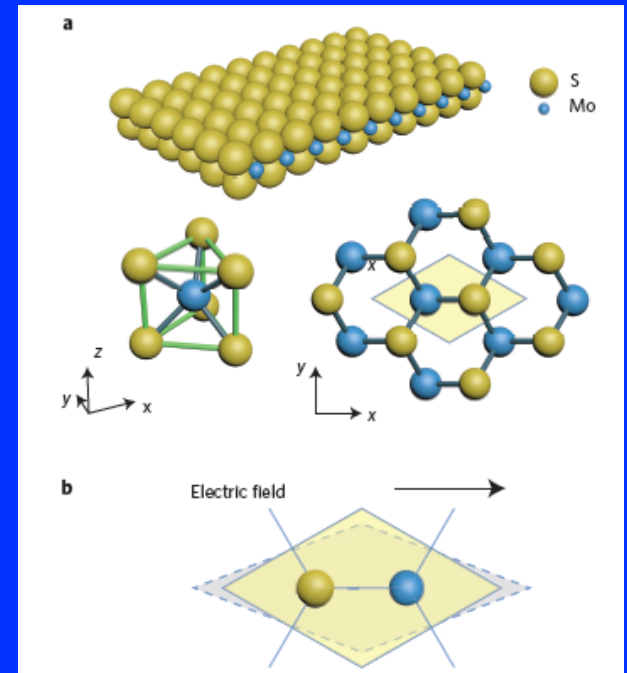
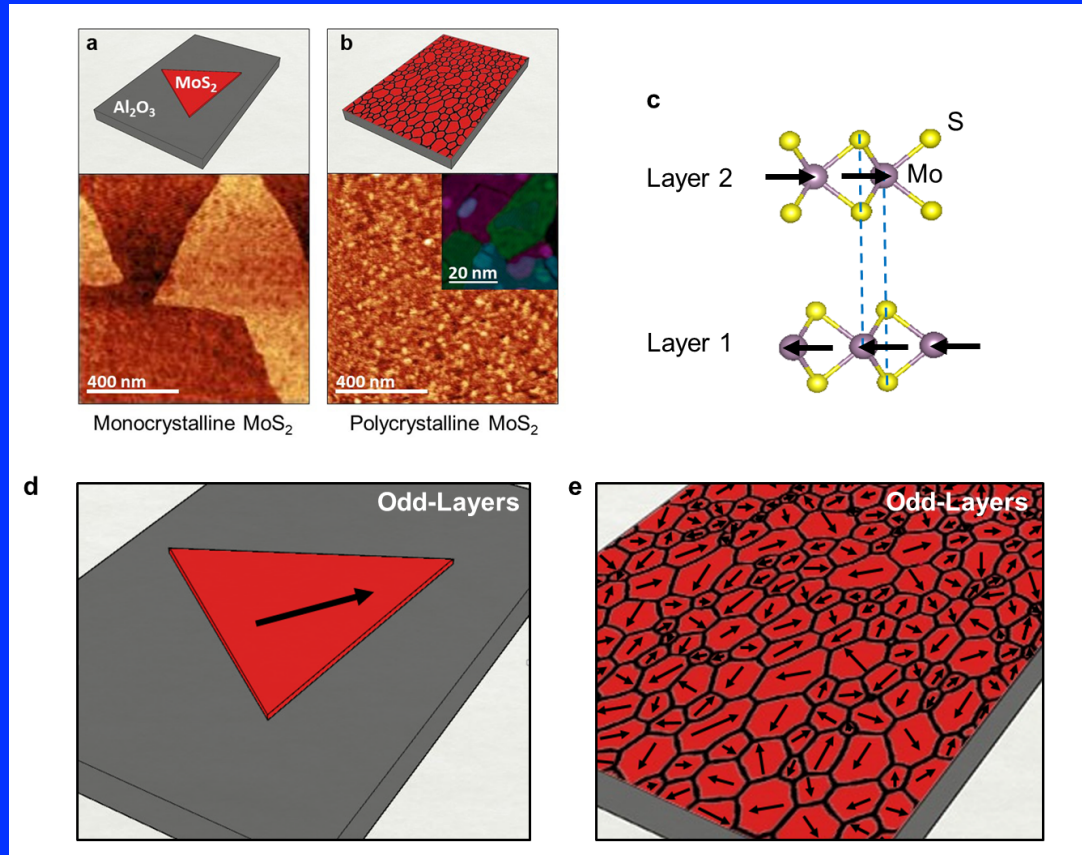


Broken Symmetry for 1 and 3 Layers: Permanent Dipole in the grains \rightarrow Water Adsorbs more!



Broken Symmetry for 1 and 3 Layers:

Permanent Dipole in the grains \rightarrow Charges at Grain Boundaries

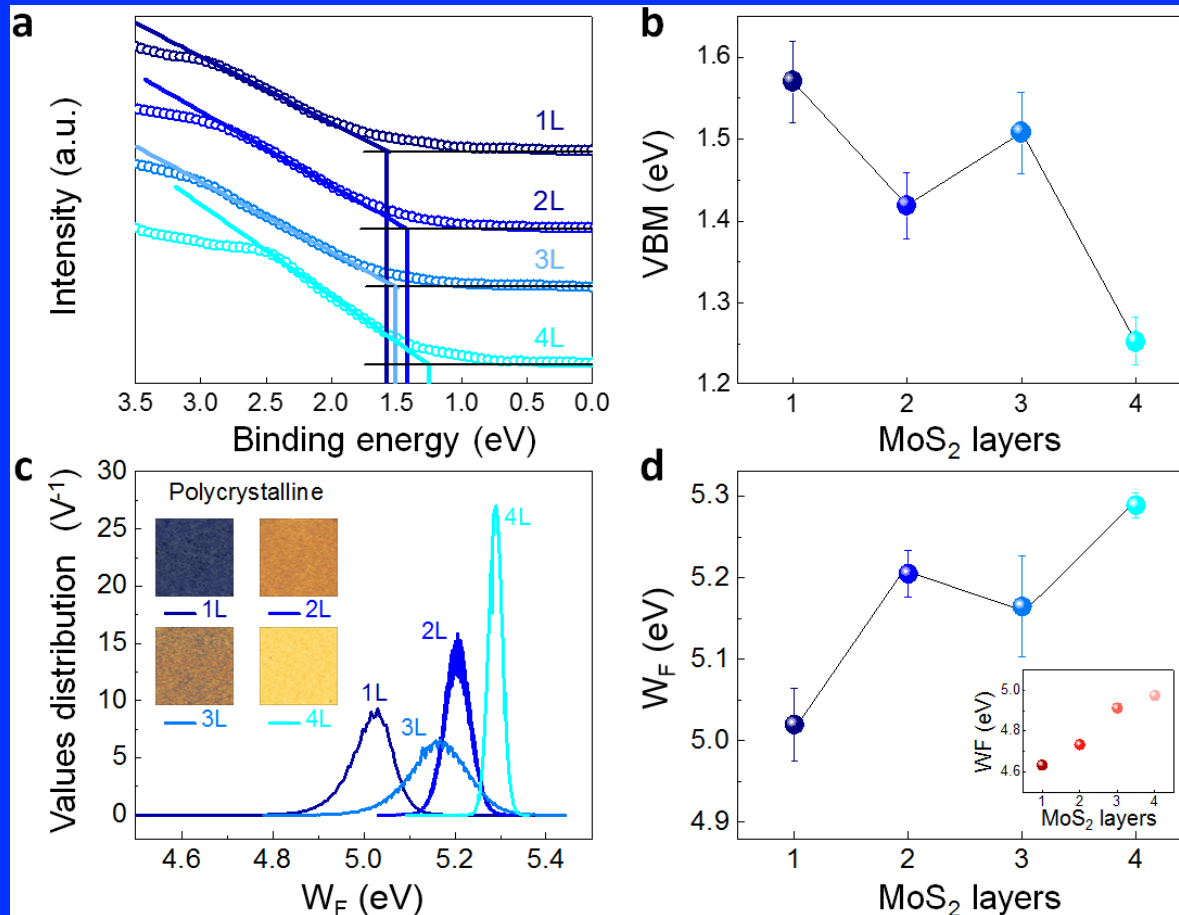


Submitted

Francesco Lavini, Annalisa Calo', Yang Gao, Edoardo Albisetti, Tai-De Li, Tengfei Cao, Linyou Cao, Carmela Aruta, and Elisa Riedo

Broken Symmetry for 1 and 3 Layers:

Permanent Dipole in the grains \rightarrow Charges at Grain Boundaries



Submitted

Francesco Lavini, Annalisa Calo', Yang Gao, Edoardo Albisetti, Tai-De Li, Tengfei Cao, Linyou Cao, Carmela Aruta, and Elisa Riedo

Conclusions

- ★ We can **measure Elastic Coupling and Van Der Waals Interaction** between atomic layers in 2D layered materials
 - ★ **Interlayer elasticity** is extremely sensitive to **intercalated molecules** e.g. water, in between the planes.
 - ★ Pressure Induced Room-temperature **diamond-stiff phase** in two-layer graphene: the fingerprint of diamene
 - ★ **Oscillatory friction** behavior for even and odd number of layers in polycrystalline MoS₂ → Permanent Dipole in the grains
-

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Riedo Group

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Edoardo Albisetti

de Heer

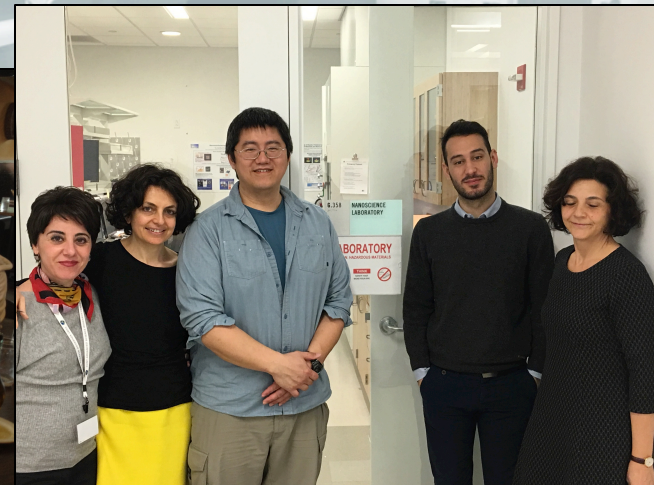
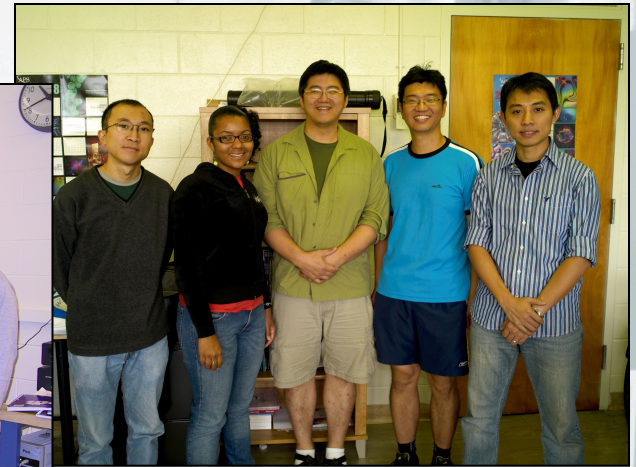
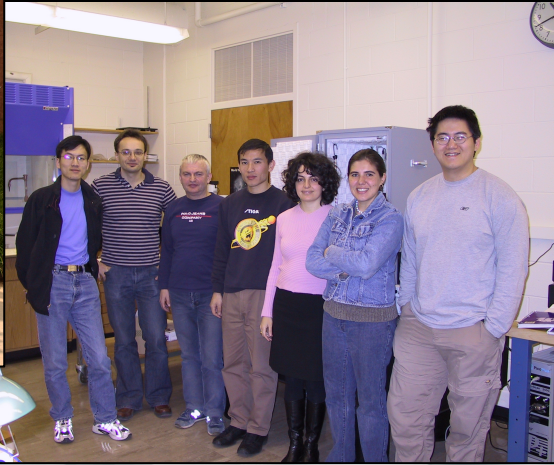
Dr. Claire Berger
Yike Hu
Xiaosong Wu
Michael W. Sprinkle

Bongiorno

Si Zhou

Tosatti @ Sissa



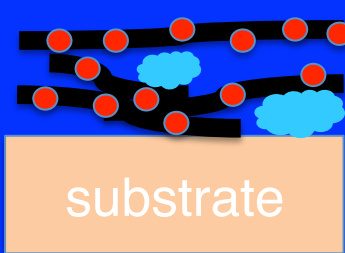


THANK YOU!

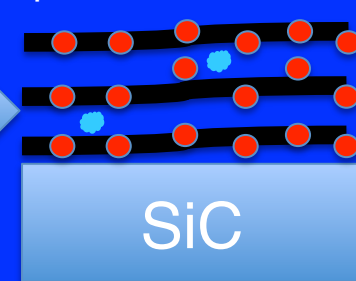
Graphene Oxide Interlayer Elasticity and Water

Relative Humidity		10 ± 2 %	15 ± 3 %	25 ± 3 %	35 ± 3 %	50 ± 3 %
E_{\perp} (GPa)	10-layer EGO	22 ± 3	-	23 ± 4	19 ± 3	22 ± 3
	Conventional GO	21 ± 6	26 ± 6	35 ± 10	-	23 ± 7
	10-layer EG	-	-	36 ± 3	-	-
	HOPG	-	-	33 ± 3	-	-

Conventional GO flakes



Epitaxial GO films

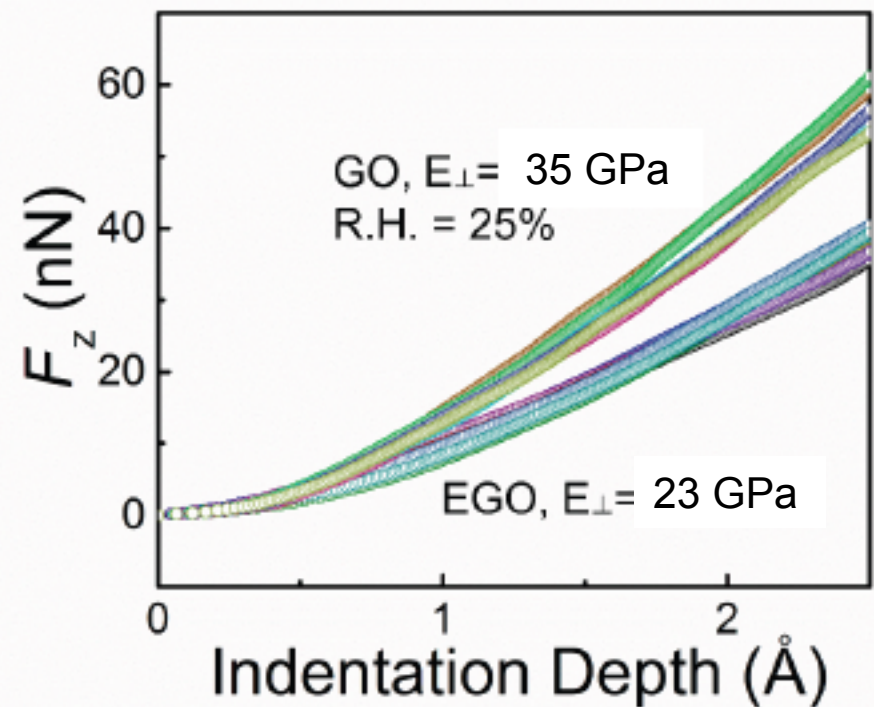


substrate

SiC

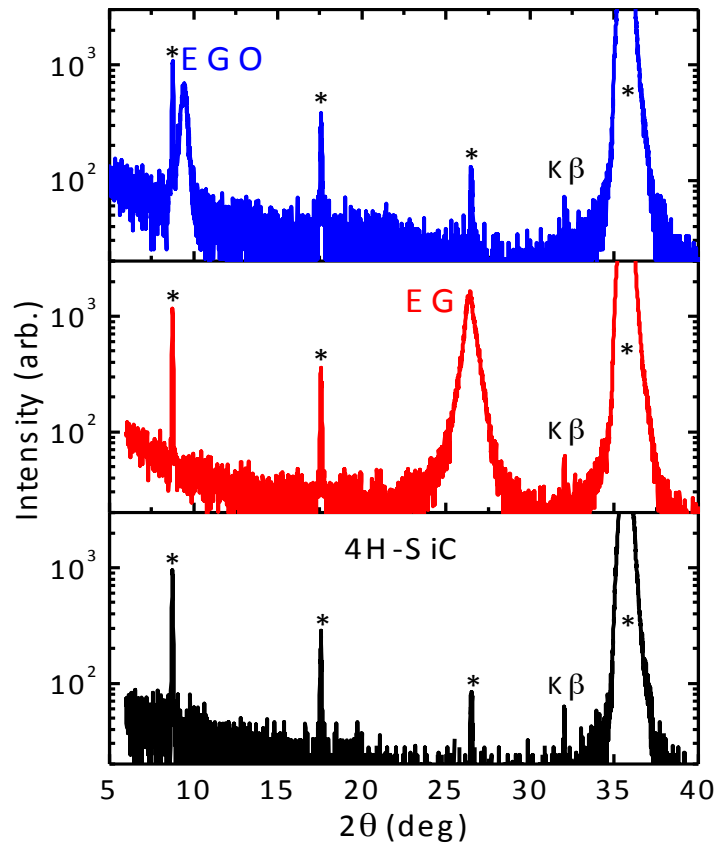
6 layers

20 μm

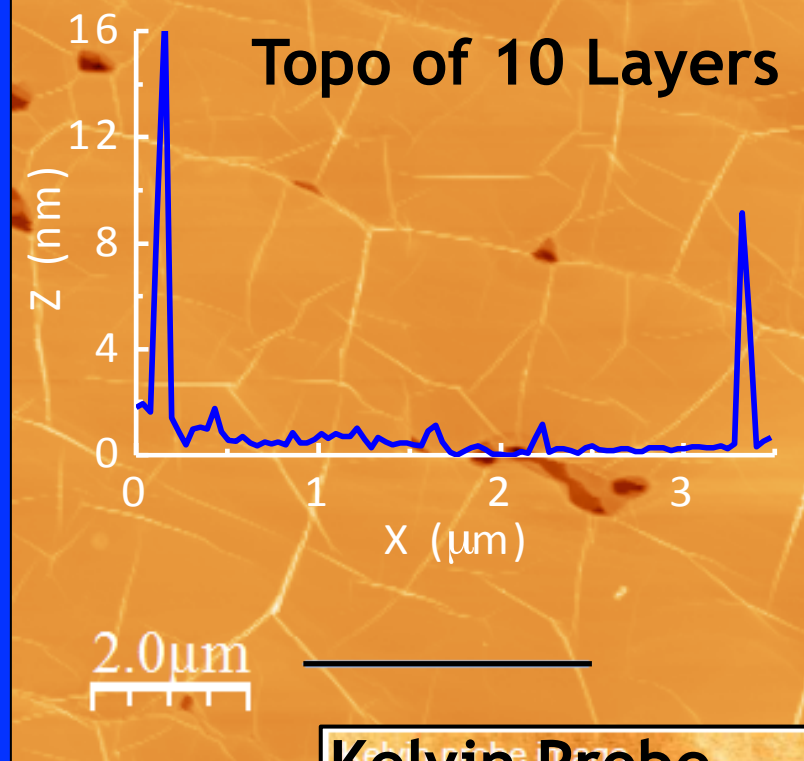


Epitaxial Multilayer GO properties

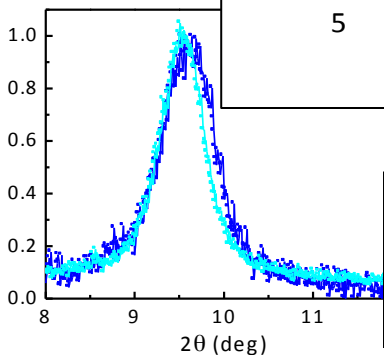
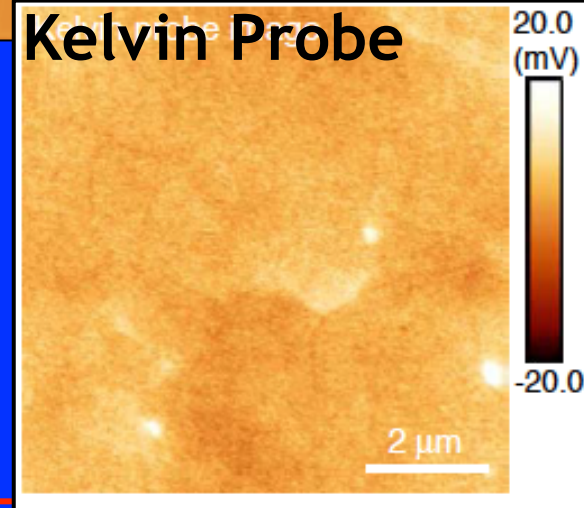
XRD of 10 Layers



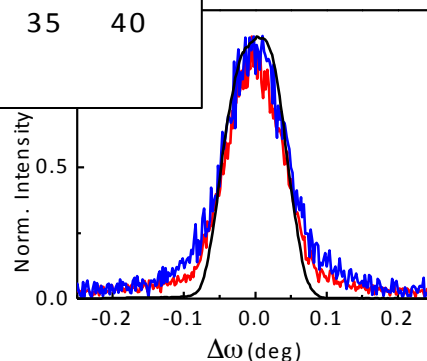
Topo of 10 Layers



Kelvin Probe



Before (dark blue)
After (Light blue)
one night in
N₂ atmosphere



Epitaxial Multilayer GO films

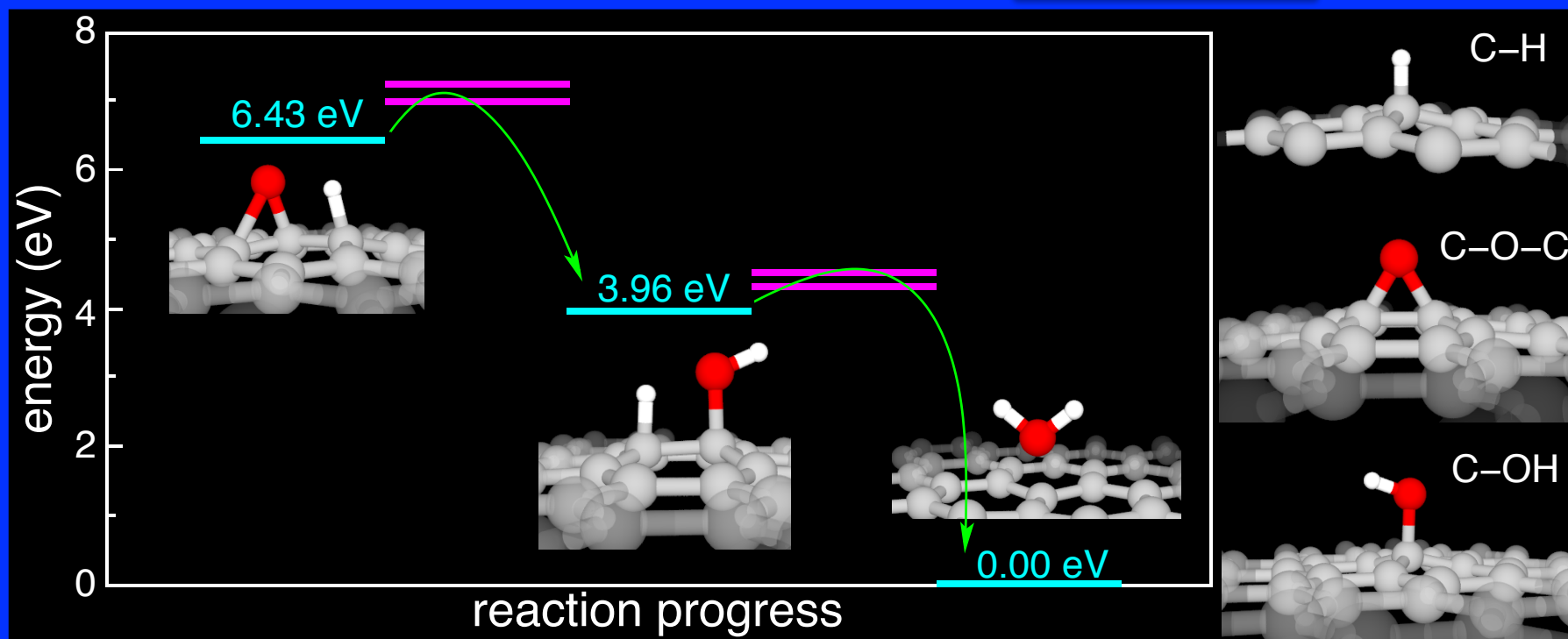
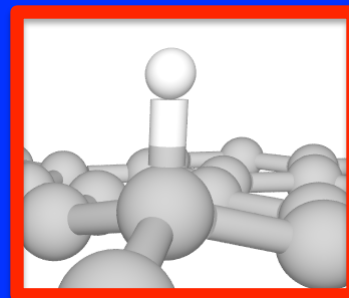
Summary

- Number of Layers : from 3 to 15
- Control over number of layers
- XPS shows about 0.4 O/C ratios
- No edges (no carboxyl groups)
- Little water, no more than 10% of C. As obtained from XPS, IR, XRD and Simulations
- Excellent Interlayer Registry
- Distance between the planes: $\sim 9.3 \text{ \AA}$

→ How can we explain $d=9.3\text{\AA}$ with so little water?

Origin of the room-temperature metastability of GO:

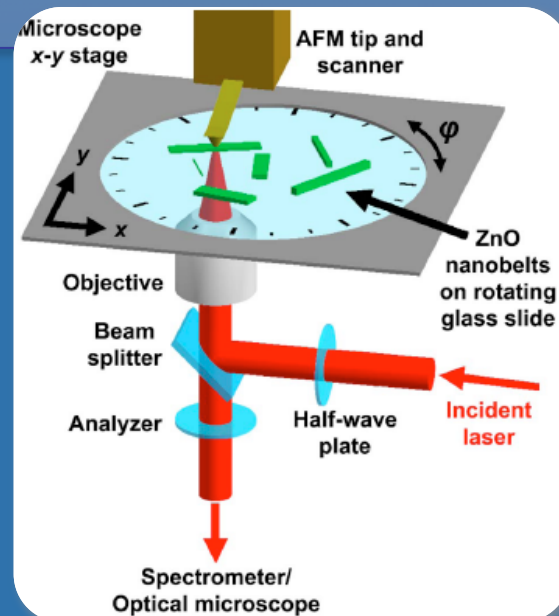
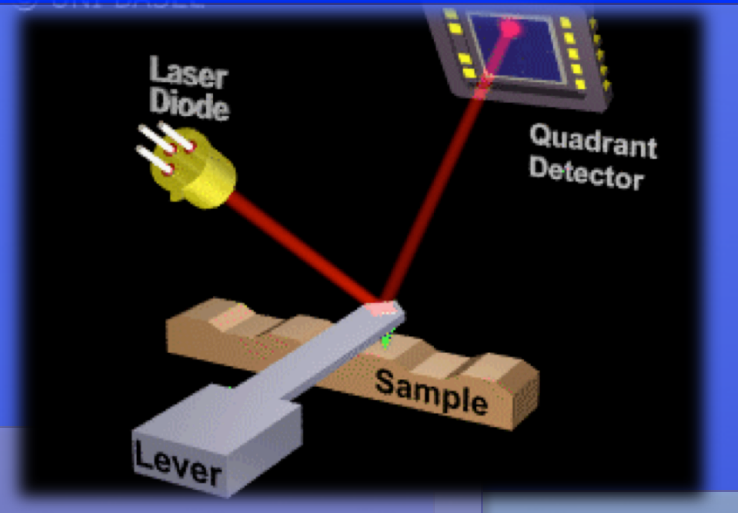
KEY ROLE of C-H groups!



Experimental methods

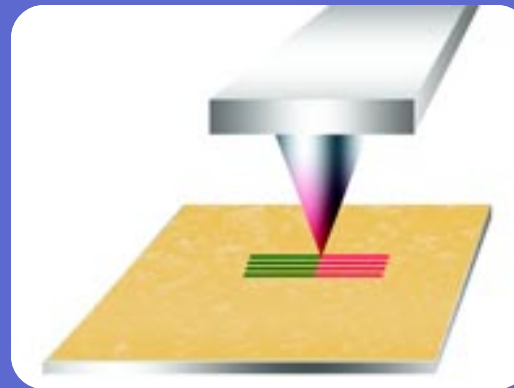
Atomic Force Microscopy (AFM):

- Topography
- Local electronic and magnetic properties
- Nanoscale Friction
- Nano-elasticity
- Nanoconfined Fluids



Combined AFM-Optical Spectroscopy

SPM-Based Nanofabrication



Facilities:

- XPS
- IR
- X-Rays
- Etc...